

MOS FET Relays

G3VM-101HR

Low 100-mΩ ON Resistance.

Higher power, 1.4-A switching with a 100-V load voltage, SOP package.

- Continuous load current of 1.4 A (connection C = 2.8 A).
- Dielectric strength of 1,500 Vrms between I/O.

RoHS compliant

⚠ Refer to "Common Precautions".

NEW

■ Application Examples

- Broadband systems
- Measurement devices
- Data loggers
- Industrial equipment

Note: The actual product is marked differently from the image shown here.

■ List of Models

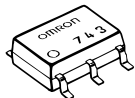
Contact form	Terminals	Load voltage (peak value) (See note.)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting terminals	100 V	G3VM-101HR	75	---
			G3VM-101HR(TR)	---	2,500

Note: The AC peak and DC value is given for the load voltage.

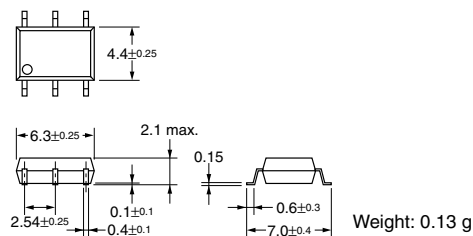
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

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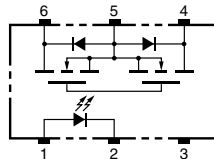


Note: The actual product is marked differently from the image shown here.



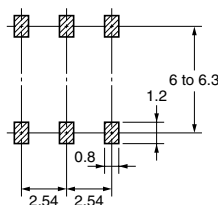
■ Terminal Arrangement/Internal Connections (Top View)

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■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

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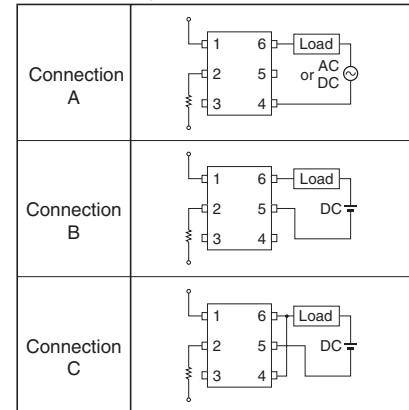


Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	I_F	30	mA	
	LED forward current reduction rate	$\Delta I_F/^\circ\text{C}$	-0.3	mA/°C	Ta ≥ 25°C
	LED reverse voltage	V_R	5	V	
	Connection temperature	T_J	125	°C	
Output	Load voltage (AC peak/DC)	V_{OFF}	100	V	
	Continuous load current	Connection A I_O	1.4	A	Connection A: AC peak/DC Connection B and C: DC
		Connection B	1.4		
		Connection C	2.8		
	ON current reduction rate	Connection A $\Delta I_O/^\circ\text{C}$	-18.7	mA/°C	Ta ≥ 50°C
		Connection B	-18.7		
		Connection C	-37.3		
	Pulse on current	I_{OP}	4	A	t = 100 ms
	Connection temperature	T_J	125	°C	
Dielectric strength between input and output (See note 1.)		V_{I-O}	1,500	Vrms	AC for 1 min
Operating temperature		T_a	-40 to +85	°C	With no icing or condensation
Storage temperature		T_{stg}	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)		---	260	°C	10 s

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

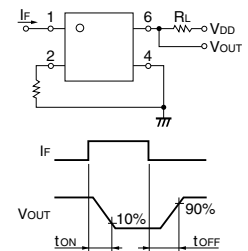
Connection Diagram



Electrical Characteristics (Ta = 25°C)

Item		Symbol	Minimum	Typical	Maximum	Unit	Measurement conditions
Input	LED forward voltage	V_F	1.18	1.33	1.48	V	$I_F = 10 \text{ mA}$
	Reverse current	I_R	---	---	10	μA	$V_R = 5 \text{ V}$
	Capacity between terminals	C_T	---	70	---	pF	$V = 0, f = 1 \text{ MHz}$
	Trigger LED forward current	I_{FT}	---	0.4	3	mA	$I_O = 100 \text{ mA}$
Output	Maximum resistance with output ON	Connection A R_{ON}	---	0.1	0.2	Ω	$I_F = 5 \text{ mA}, I_O = 1.4 \text{ A}, t < 1 \text{ s}$
		Connection B	---	0.05	0.1	Ω	$I_F = 5 \text{ mA}, I_O = 1.4 \text{ A}, t < 1 \text{ s}$
		Connection C	---	0.025	---	Ω	$I_F = 5 \text{ mA}, I_O = 2.8 \text{ A}, t < 1 \text{ s}$
	Current leakage when the relay is open	I_{LEAK}	---	---	10	nA	$V_{OFF} = 100 \text{ V}$
Capacity between I/O terminals		C_{I-O}	---	0.8	---	pF	$f = 1 \text{ MHz}, V_s = 0 \text{ V}$
Insulation resistance		R_{I-O}	1,000	---	---	MΩ	$V_{I-O} = 500 \text{ VDC}, \text{RoH} \leq 60\%$
Turn-ON time		t_{ON}	---	1.0	5.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \text{ Ω}, V_{DD} = 20 \text{ V}$ (See note 2.)
Turn-OFF time		t_{OFF}	---	0.15	1.0	ms	

Note: 2. Turn-ON and Turn-OFF Times



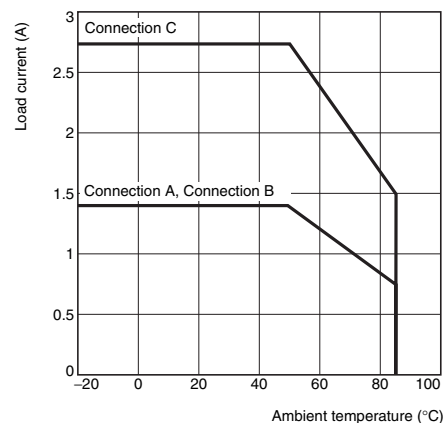
Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Load voltage (AC peak/DC)	V_{DD}	---	---	100	V
Operating LED forward current	I_F	5	7.5	20	mA
Continuous load current (AC peak/DC)	I_O	---	---	1.1	A
Operating temperature	T_a	-20	---	65	°C

Engineering Data

Load Current vs. Ambient Temperature G3VM-101HR



Safety Precautions

Refer to "Common Precautions" for all G3VM models.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9